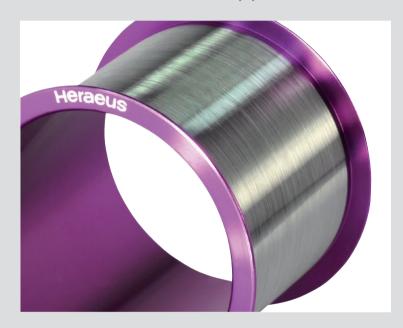
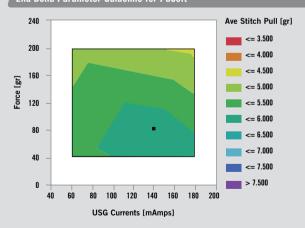
Heraeus



Palladium Coated Copper Wire for IC Applications



2nd Bond Parameter Guideline for PdSoft



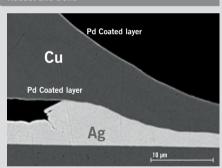
Fixed: Bonding time: 15 msec CV: 0.4 Device: PBGA 2x2 Test Die, Wire Diameter: 0.8 mil PdSoft, Bonder: K&S Maxum Ultra, Bonding Temp.: 175°C Capillary: K&S CU-FF-1115-P37 (T2.7)

Pason Benefits and Features

- Improved performance
- Robust 2nd bond
- D 11 1 111
- ft FAR characteristics
- Simplified handling
- Longer floor/shelf life
- Ovidation protection
- Workable with N₂ gas

Robust 2nd Bond

70



Pd Layer at the wire-substrate interface enhance ability to bond

Wire Diameter: 18 μ m, EFO current: 60 mA, FAB Diameter: 30 μ m, Bonder: K&S iConn

Ref. CuPd

Pdsoft

Recommended Technical Data of <i>Pdām</i>											
Diameter	Microns (µm)	15	18	20	23	25	28	30	33	38	50
	Mils	0.6	0.7	0.8	0.9	1	1.1	1.2	1.3	1.5	2
Elongation	(%)	8 – 14	9 – 15	11 – 17	13 – 19	13 - 21	13 – 25	13 – 25	13 – 25	13 – 25	13 – 25
Breaking Load	(g)	2 – 7	3 – 8	4 – 10	6 – 12	8 - 14	11 - 18	14 – 21	18 - 25	24 – 35	48 – 60

For other diameters, please contact Heraeus Bonding Wires sales representative.

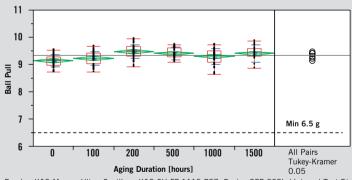
Heraeus

Point Characteristics for 0.8 mil diameter

Physical Properties						
Density	8.99 g/cm ³					
Melting Point *	1083 °C					
Thermal Conductivity *	401 W/m.K					
Specific Heat Capacity @ 25C *	385 J/kg.K					
Coeff. of Thermal Expansion *	$16.5 \ \mu \text{m/m}^{\circ}\text{C}, (20 - 100^{\circ}\text{C})$					
Specific Electrical Resistivity	1.7 μΩ -cm					
FAB Hardness (60 mA EFO)	90 – 105 HV (0.01 N/5 s)					
Wire Hardness*	95 – 105 HV (0.01 N/5 s)					
Elastic Modulus	95 – 105 GPa					
Chemical Composition						
Copper	99.99 % min					
Pd	1.3 % – 2.9 %					
Mechanical Properties						
Elongation	11 – 17 %					
Break Load	4 – 10 g					
Other Guidelines						
Floor Life	60 days					
Shelf Life Time	6 months					
Shielding Gas	N ₂ / Forming Gas					

Ball Pull Result HTS 175°C up to 1500 hrs

* Based on Core Material



Bonder: K&S Maxum Ultra, Capillary: K&S CU-FF-1115-P37, Device QFP 208L / Internal Test Die Al-1 % Si-0.5 % Cu, Al10,000Å. Ball Diameter: \sim 40 μm , PdSoft 0.8 mil

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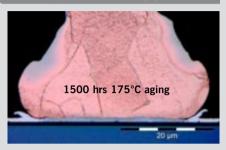
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Good Reliability under Isothermal aging



Slow and stable Intermetallic growth Passed HTS 1500 hrs 175°C (unmolded device)

Extreme Wire Corrosion Test

Condition: Corrosive fume environment at RT Duration: 336 hrs

PdSoft Copper Wire



No oxidation found on wire surface

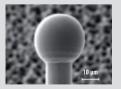
Bare Copper Wire



Severe oxidation found on wire surface

Consistent FAB roundness in N₂ environment

FAB Target: $\sim 26 \text{um}$, Wire Diameter: 0.6 mil PdSoft, Bonder: K&S Iconn, EFO Current: 60 mA, N_2 Gas Flow Rate: 0.3 \sim 0.5 l/min



FAB Target: ~ 40 µm, Wire Diameter: 0.8 mil PdSoft, Bonder: K&S Maxum Ultra, EFO Current: 60 mA, N₂ Gas Flow Rate: 0.3 ~ 0.6 l/min

